## **INTEGRATED CIRCUITS**

# DATA SHEET

# **TSA5511**1.3 GHz Bidirectional I<sup>2</sup>C-bus controlled synthesizer

Product specification
File under Integrated Circuits, IC02

October 1992





### 1.3 GHz Bidirectional I<sup>2</sup>C-bus controlled synthesizer

**TSA5511** 

#### **FEATURES**

- Complete 1.3 GHz single chip system
- Low power 5 V, 35 mA
- I<sup>2</sup>C-bus programming
- In-lock flag
- Varicap drive disable
- Low radiation
- Address selection for Picture-In-Picture (PIP), DBS tuner (3 addresses)
- · Analog-to-digital converter
- 8 bus controlled ports (5 for TSA5511T), 4 current limited outputs (1 for TSA5511T), 4 open collector outputs (bi-directional)
- Power-down flag

#### **APPLICATIONS**

- TV tuners
- VCR Tuners



#### **GENERAL DESCRIPTION**

The TSA5511 is a single chip PLL frequency synthesizer designed for TV tuning systems. Control data is entered via the I<sup>2</sup>C-bus; five serial bytes are required to address the device, select the oscillator frequency, programme the eight output ports and set the charge-pump current. Four of these ports can also be used as input ports (three general purpose I/O ports, one ADC). Digital information concerning those ports can be read out of the TSA5511 on the SDA line (one status byte) during a READ operation. A flag is set when the loop is "in-lock" and is read during a READ operation. The device has one fixed I<sup>2</sup>C-bus address and 3 programmable addresses, programmed by applying a specific voltage on Port 3. The phase comparator operates at 7.8125 kHz when a 4 MHz crystal is used.

#### **ORDERING INFORMATION**

EXTENDED TYPE	PACKAGE						
NUMBER	PINS	PIN POSITION	MATERIAL	CODE			
TSA5511	18	DIL	plastic	SOT102 <sup>(1)</sup>			
TSA5511T	16	SO	plastic	SOT109A <sup>(2)</sup>			
TSA5511AT	20	SO	plastic	SOT163A <sup>(3)</sup>			

#### Note

- 1. SOT102-1; 1996 December 5.
- 2. SOT109-1; 1996 December 5.
- 3. SOT163-1; 1996 December 5.

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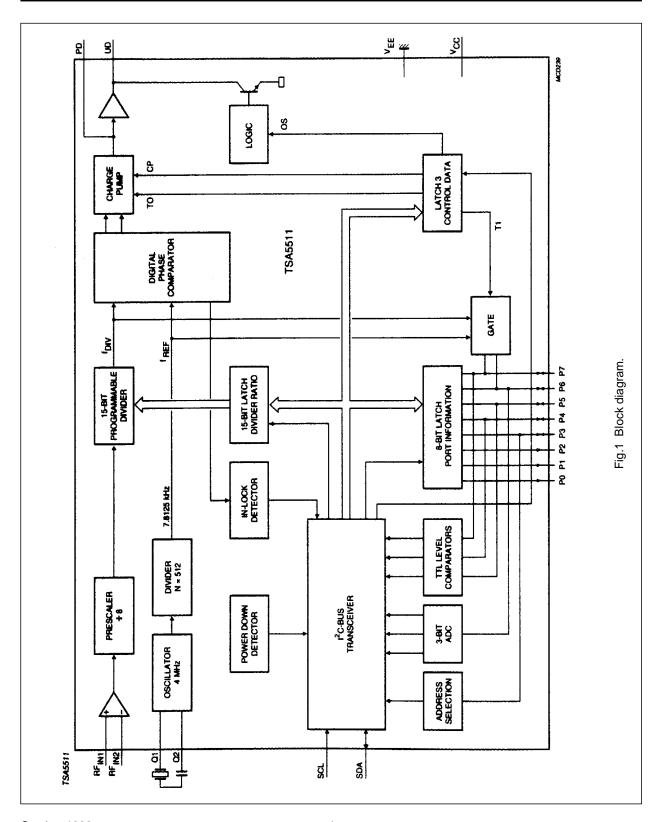
TSA5511

#### **QUICK REFERENCE DATA**

SYMBOL	PARAMETER	MIN.	TYP.	MAX.	UNIT
V <sub>CC</sub>	positive supply voltage	-	5	_	V
Icc	supply current	-	35	_	mA
Δf	frequency range	64	_	1300	MHz
VI	input voltage level				
	80 MHz to 150 MHz	12	_	300	mV
	150 MHz to 1 GHz	9	_	300	mV
	1 GHz to 1.3 GHz	40	_	300	mV
f <sub>XTAL</sub>	crystal oscillator frequency	3.2	4.0	4.48	MHz
Io	open-collector output current	10	_	_	mA
Io	current-limited output current	-	1	_	mA
T <sub>amb</sub>	operating ambient temperature range	-10	_	+80	°C
T <sub>stg</sub>	IC storage temperature range	-40	_	+150	°C

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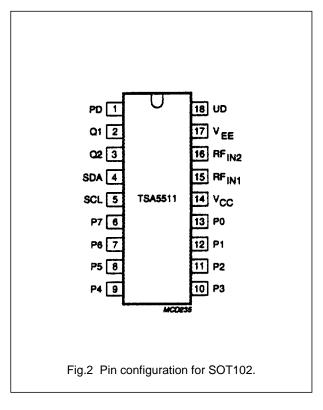
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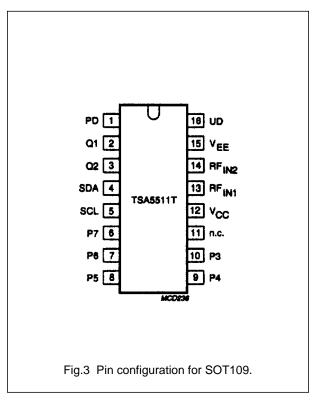


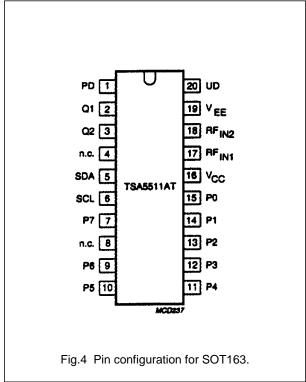
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#### **PINNING**

SYMBOL		PIN		DESCRIPTION
STIVIBUL	SOT102	SOT109	SOT163	DESCRIPTION
PD	1	1	1	charge-pump output
Q1	2	2	2	crystal oscillator input 1
Q2	3	3	3	crystal oscillator reference voltage
n.c.	_	-	4	not connected
SDA	4	4	5	serial data input/output
SCL	5	5	6	serial clock input
P7	6	6	7	port output/input (general purpose)
n.c.	-	-	8	not connected
P6	7	7	9	port output/input for general purpose ADC
P5	8	8	10	port output/input (general purpose)
P4	9	9	11	port output/input (general purpose)
P3	10	10	12	port output/input for address selection
P2	11	-	13	port output
n.c.	-	11	-	not connected
P1	12	-	14	port output
P0	13	-	15	port output
V <sub>CC</sub>	14	12	16	voltage supply
RF <sub>IN1</sub>	15	13	17	UHF/VHF signal input 1
RF <sub>IN2</sub>	16	14	18	UHF/VHF signal input 2 (decoupled)
V <sub>EE</sub>	17	15	19	ground
UD	18	16	20	drive output

#### **FUNCTIONAL DESCRIPTION**

The TSA5511 is controlled via the two-wire  $I^2C$ -bus. For programming, there is one module address (7 bits) and the  $R/\overline{W}$  bit for selecting READ or WRITE mode.

#### WRITE mode : $R/\overline{W} = 0$ (see Table 1)

After the address transmission (first byte), data bytes can be sent to the device. Four data bytes are required to fully program the TSA5511. The bus transceiver has an auto-increment facility which permits the programming of the TSA5511 within one single transmission (address + 4 data bytes).

The TSA5511 can also be partially programmed on the condition that the first data byte following the address is byte 2 or byte 4. The meaning of the bits in the data bytes is given in Table 1. The first bit of the first data byte transmitted indicates whether frequency data (first bit = 0) or charge pump and port information (first bit = 1) will follow. Until an  $I^2C$ -bus STOP condition is sent by the controller, additional data bytes can be entered without the need to re-address the device. This allows a smooth frequency sweep for fine tuning or AFC purposes. At power-on the ports are set to the high impedance state.

The 7.8125 kHz reference frequency is obtained by dividing the output of the 4 MHz crystal oscillator by 512. Because the input of UHF/VHF signal is first divided by 8 the step size is 62.5 kHz. A 3.2 MHz crystal can offer step sizes of 50 kHz.

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Table 1 Write data format

	MSB							LSB		
Address	1	1	0	0	0	MA1	MA0	0	Α	byte 1
Programmable divider	0	N14	N13	N12	N11	N10	N9	N8	А	byte 2
Programmable divider	N7	N6	N5	N4	N3	N2	N1	N0	А	byte 3
Charge-pump and test bits	1	СР	T1	T0	1	1	1	os	А	byte 4
Output ports control bits	P7	P6	P5	P4	P3	P2*	P1*	P0*	А	byte 5

#### Note to Table 1

\* not valid for TSA5511T

MA1, MA0 programmable address bits (see Table 4)

A acknowledge bit

N14 to N0 programmable divider bits  $N = N14 \times 2^{14} + N13 \times 2^{13} + ... + N1 \times 2^{1} + N0$ 

CP charge-pump current

 $\begin{aligned} \text{CP} &= 0 & \text{50 } \mu \text{A} \\ \text{CP} &= 1 & \text{220 } \mu \text{A} \end{aligned}$ 

P3 to P0 = 1 limited-current output is active
P7 to P4 = 1 open-collector output is active
P7 to P0 = 0 outputs are in high impedance state

T1, T0, OS = 0 0 0 normal operation T1 = 1  $P6 = f_{ref}, P7 = f_{DIV}$  T0 = 1 3-state charge-pump

OS =1 operational amplifier output is switched off (varicap drive disable)

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#### READ mode : $R/\overline{W} = 1$ (see Table 2)

Data can be read out of the TSA5511 by setting the  $R/\overline{W}$  bit to 1. After the slave address has been recognized, the TSA5511 generates an acknowledge pulse and the first data byte (status word) is transferred on the SDA line (MSB first). Data is valid on the SDA line during a high position of the SCL clock signal.

A second data byte can be read out of the TSA5511 if the processor generates an acknowledge on the SDA line. End of transmission will occur if no acknowledge from the processor occurs.

The TSA5511 will then release the data line to allow the processor to generate a STOP condition.

When ports P3 to P7 are used as inputs, they must be programmed in their high-impedance state.

The POR flag (power-on reset) is set to 1 when  $V_{CC}$  goes below 3 V and at power-on. It is reset when an end of data is detected by the TSA5511 (end of a READ sequence).

Control of the loop is made possible with the in-lock flag FL which indicates (FL = 1) when the loop is phase-locked. The bits I2, I1 and I0 represent the status of the I/O ports P7, P5 and P4 respectively. A logic 0 indicates a LOW level and a logic 1 a HIGH level (TTL levels).

A built-in 5-level ADC is available on I/O port P6. This converter can be used to feed AFC information to the controller from the IF section of the television as illustrated in the typical application circuit (Fig.5). The relationship between bits A2, A1 and A0 and the input voltage on port P6 is given in Table 3.

Table 2 Read data format

	MSB							LSB		
Address	1	1	0	0	0	MA1	MA0	1	Α	byte 1
Status byte	POR	FL	12	I1	10	A2	A1	A0	_	byte 2

#### Note to Table 2

POR power-on reset flag. (POR = 1 on power-on)

FL in-lock flag (FL = 1 when the loop is phase-locked)

I2, I1, I0 digital information for I/O ports P7, P5 and P4 respectively

A2, A1, A0 digital outputs of the 5-level ADC. Accuracy is 1/2 LSB (see Table 3)

MSB is transmitted first.

#### Address selection

The module address contains programmable address bits (MA1 and MA0) which together with the I/O port P3 offers the possibility of having several synthesizers (up to 3) in one system.

The relationship between MA1 and MA0 and the input voltage I/O port P3 is given in Table 4.

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Table 3 ADC levels

VOLTAGE APPLIED ON THE PORT P6	A2	A1	A0
0.6 V <sub>CC</sub> to 13.5 V	1	0	0
0.45 V <sub>CC</sub> to 0.6 V <sub>CC</sub>	0	1	1
0.3 V <sub>CC</sub> to 0.45 V <sub>CC</sub>	0	1	0
0.15 V <sub>CC</sub> to 0.3 V <sub>CC</sub>	0	0	1
0 to 0.15 V <sub>CC</sub>	0	0	0

Table 4 Address selection

MA1	MA0	VOLTAGE APPLIED ON PORT P3			
0	0	0 to 0.1 V <sub>CC</sub>			
0	1	always valid			
1	0	0.4 to 0.6 V <sub>CC</sub>			
1	1	0.9 V <sub>CC</sub> to 13.5 V			

#### **LIMITING VALUES**

In accordance with Absolute Maximum Rating System (IEC 134); all pin numbers refer to DIL18 version

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
V <sub>CC</sub>	supply voltage	-0.3	6	V
V <sub>1</sub>	charge-pump output voltage	-0.3	V <sub>CC</sub>	V
V <sub>2</sub>	crystal (Q1) input voltage	-0.3	V <sub>CC</sub>	V
V <sub>4</sub>	serial data input/output voltage	-0.3	6	V
V <sub>5</sub>	serial clock input voltage	-0.3	6	V
V <sub>6-13</sub>	P7 to P0 input/output voltage	-0.3	+16	V
V <sub>15</sub>	prescaler input voltage	-0.3	V <sub>CC</sub>	V
V <sub>18</sub>	drive output voltage	-0.3	V <sub>CC</sub>	V
I <sub>6-9</sub>	P7 to P4 output current (open collector)	-1	15	mA
I <sub>4</sub>	SDA output current (open collector)	-1	5	mA
T <sub>stg</sub>	IC storage temperature range	-40	+150	°C
Tj	maximum junction temperature	_	150	°C

#### THERMAL RESISTANCE

SYMBOL	PARAMETER	THERMAL RESISTANCE
R <sub>th j-a</sub>	from junction to ambient in free air	
	DIL18	80 K/W
	SO16	110 K/W
	SO20	80 K/W

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#### **CHARACTERISTICS**

 $V_{CC}$  = 5 V;  $T_{amb}$  = 25 °C, unless otherwise specified All pin numbers refer to DIL18 version

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Functiona	ıl range			'		
V <sub>CC</sub>	supply voltage range		4.5	_	5.5	V
T <sub>amb</sub>	operating ambient temperature range		-10	-	+80	°C
f	input frequency		64	_	1300	MHz
N	divider		256	_	32767	
Icc	supply current		25	35	50	mA
f <sub>XTAL</sub>	crystal oscillator frequency range	crystal series resonance resistance $\leq$ 150 $\Omega$	3.2	4.0	4.48	MHz
Z <sub>I</sub>	input impedance (pin 2)		-480	-400	-320	Ω
	input level	$V_{CC}$ = 4.5 V to 5.5 V; $T_{amb}$ = -10 to +80 °C; see typical sensitivity curve Fig.6				
	f = 80 to 150 MHz		12/–25	_	300/2.6	mV/dBm
	f = 150 to 1000 MHz		9/–28	_	300/2.6	mV/dBm
	f = 1000 to 1300 MHz		40/–15	_	300/2.6	mV/dBm
R <sub>I</sub>	prescaler input resistance (see Fig.7)		_	50	_	Ω
C <sub>I</sub>	input capacitance		_	2	_	pF
Output po	orts (current-limited) P0 to P	3				
I <sub>LO</sub>	output leakage current	V <sub>O</sub> = 13.5 V	_	_	10	μΑ
I <sub>sink</sub>	output sink current	V <sub>O</sub> = 12 V	0.7	1.0	1.5	mA
Output po	orts (open collector) P4 to P7	7 (see note 1)	·	·	·	·
I <sub>LO</sub>	output leakage current	V <sub>O</sub> = 13.5 V	-	_	10	μΑ
V <sub>OL</sub>	LOW level output voltage	I <sub>OL</sub> = 10 mA; note 2	_	_	0.7	V
Input port	: P3		•	•	•	•
I <sub>OH</sub>	HIGH level input current	V <sub>OH</sub> = 13.5 V	-	_	10	μΑ
I <sub>OL</sub>	LOW level input current	V <sub>OL</sub> = 0 V	-10	_	_	μΑ
Input port	s P4, P5 and P7			•		
V <sub>IL</sub>	LOW level input voltage		_	_	0.8	V
V <sub>IH</sub>	HIGH level input voltage		2.7	_	_	V
I <sub>IH</sub>	HIGH level input current	V <sub>IH</sub> = 13.5 V	_	_	10	μΑ
I <sub>IL</sub>	LOW level input current	V <sub>IL</sub> = 0 V	-10	_	_	μΑ
Input port	P6					
I <sub>IH</sub>	HIGH level input current	V <sub>IH</sub> = 13.5 V	_	_	10	μΑ
I <sub>IL</sub>	LOW level input current	V <sub>IL</sub> = 0 V	-10	_	-	μΑ
_						

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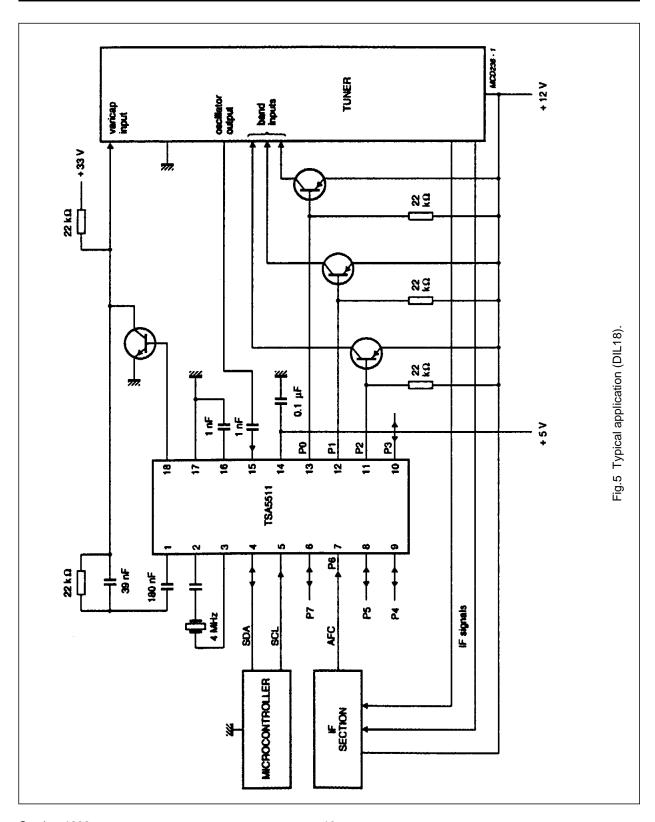
SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
SCL and S	SDA inputs			•	•	•
V <sub>IH</sub>	HIGH level input voltage		3.0	_	5.5	V
V <sub>IL</sub>	LOW level input voltage		_	_	1.5	V
I <sub>IH</sub>	HIGH level input current	V <sub>IH</sub> = 5 V; V <sub>CC</sub> = 0 V	_	_	10	μΑ
		$V_{IH} = 5 \text{ V}; V_{CC} = 5 \text{ V}$	_	_	10	μΑ
I <sub>IL</sub>	LOW level input current	V <sub>IL</sub> = 0 V; V <sub>CC</sub> = 0 V	-10	_	_	μΑ
		$V_{IL} = 0 \text{ V}; V_{CC} = 5 \text{ V}$	-10	_	_	μΑ
Output SE	OA (pin 4; open collector)		·		·	·
I <sub>LO</sub>	output leakage current	V <sub>O</sub> = 5.5 V	-	_	10	μΑ
Vo	output voltage	I <sub>O</sub> = 3 mA	_	_	0.4	V
Charge-pu	ımp output PD (pin 1)			•	•	•
I <sub>OH</sub>	HIGH level output current (absolute value)	CP = 1	90	220	300	μΑ
I <sub>OL</sub>	LOW level output current (absolute value)	CP = 0	22	50	75	μΑ
V <sub>1</sub>	output voltage	in-lock	1.5	_	2.5	V
I <sub>1leak</sub>	off-state leakage current	T0 = 1	-5	_	5	nA
Operation	al amplifier output UD (test	mode T0 = 1)				•
V <sub>18</sub>	output voltage	V <sub>IL</sub> = 0 V	_	_	100	mV
V <sub>18</sub>	output voltage when switched-off	OS = 1; V <sub>IL</sub> = 2 V	_	_	200	mV
G	operational amplifier current gain; I <sub>18</sub> /(I <sub>1</sub> - I <sub>1leak</sub> )	OS = 0; $V_{IL} = 2 V$ ; $I_{18} = 10 \mu A$	2000	_	-	

#### Notes to the characteristics

- 1. When a port is active, the collector voltage must not exceed 6 V.
- 2. Measured with a single open-collector port active.

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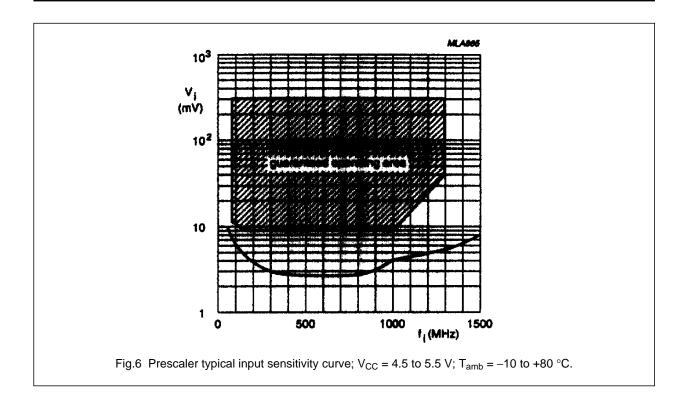
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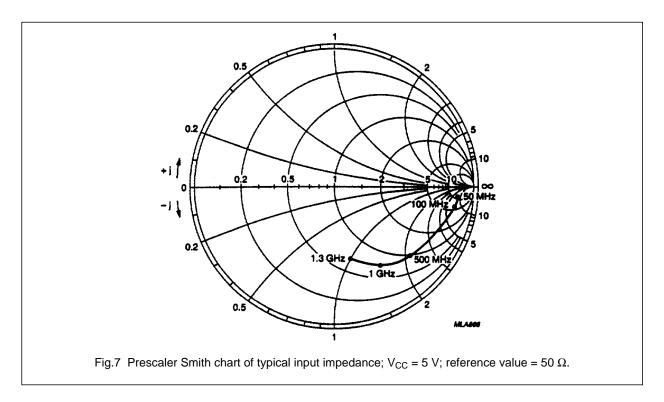


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#### **FLOCK FLAG DEFINITION (FL)**

When the FL flag is 1, the maximum frequency deviation ( $\Delta f$ ) from stable frequency can be expressed as follows:

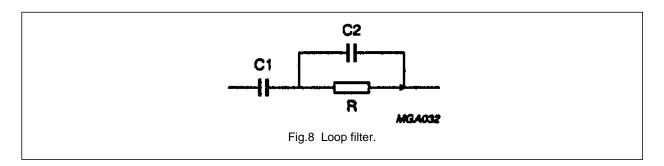
$$\Delta f = \pm \; (K_{VCO}/K_O) \times I_{CP} \times (C1 + C2) \, / \, (C1 \times C2)$$

#### Where:

 $K_{VCO}$  = oscillator slope (Hz/V)  $I_{CP}$  = charge-pump current (A)

 $K_O = 4 \times 10E6$ 

C1 and C2 = loop filter capacitors (see Fig.8)



#### **FLOCK FLAG APPLICATION**

- K<sub>VCO</sub> = 16 MHz/V (UHF band)
- $I_{CP} = 220 \, \mu A$
- C1 = 180 nF
- C2 = 39 nF
- $\Delta f = \pm 27.5 \text{ kHz}.$

Table 5 Flock flag settings

	MIN.	MAX.	UNIT
Time span between actual phase lock and FL-flag setting	1024	1152	μs
Time span between the loop losing lock and FL-flag resetting	0	128	μs

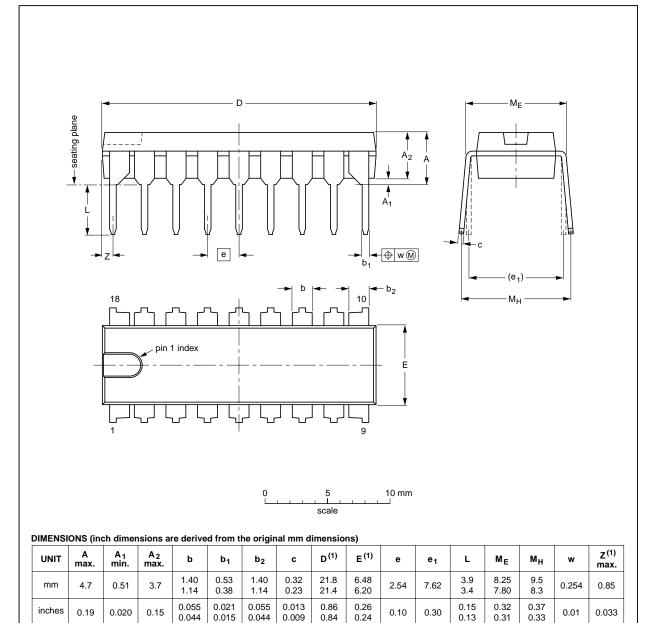
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#### **PACKAGE OUTLINES**

#### DIP18: plastic dual in-line package; 18 leads (300 mil)

SOT102-1



#### Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

OUTLINE	REFERENCES				EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE
SOT102-1						<del>93-10-14</del> 95-01-23

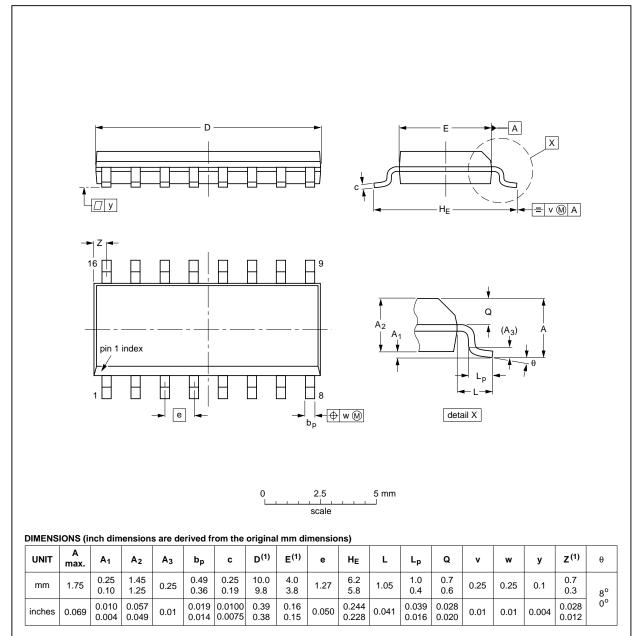
Downloaded from Elcodis.com electronic components distributor

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#### SO16: plastic small outline package; 16 leads; body width 3.9 mm

SOT109-1



#### Note

1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.

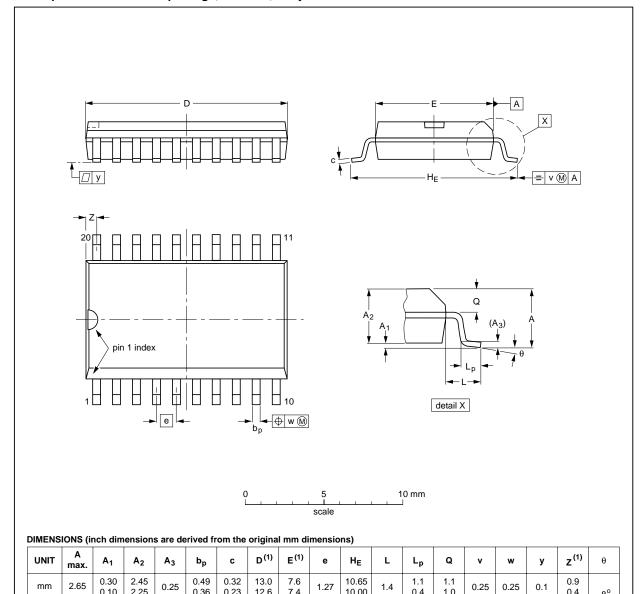
OUTLINE	REFERENCES			EUROPEAN	ISSUE DATE	
VERSION	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE
SOT109-1	076E07S	MS-012AC				<del>95-01-23</del> 97-05-22

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#### SO20: plastic small outline package; 20 leads; body width 7.5 mm

SOT163-1



#### Note

inches

0.012

0.004

0.10

0.096

0.089

1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.

0.013

0.009

0.51

0.49

0.019

0.014

OUTLINE	REFERENCES				EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE
SOT163-1	075E04	MS-013AC				<del>-95-01-24</del> 97-05-22

0.050

0.30

0.29

0.419 0.394 0.043

0.039

0.01

0.01

0.004

0.043

0.016

0.035

0.016

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#### **SOLDERING**

#### Introduction

There is no soldering method that is ideal for all IC packages. Wave soldering is often preferred when through-hole and surface mounted components are mixed on one printed-circuit board. However, wave soldering is not always suitable for surface mounted ICs, or for printed-circuits with high population densities. In these situations reflow soldering is often used.

This text gives a very brief insight to a complex technology. A more in-depth account of soldering ICs can be found in our "IC Package Databook" (order code 9398 652 90011).

#### DIP

#### SOLDERING BY DIPPING OR BY WAVE

The maximum permissible temperature of the solder is 260 °C; solder at this temperature must not be in contact with the joint for more than 5 seconds. The total contact time of successive solder waves must not exceed 5 seconds.

The device may be mounted up to the seating plane, but the temperature of the plastic body must not exceed the specified maximum storage temperature (T<sub>stg max</sub>). If the printed-circuit board has been pre-heated, forced cooling may be necessary immediately after soldering to keep the temperature within the permissible limit.

#### REPAIRING SOLDERED JOINTS

Apply a low voltage soldering iron (less than 24 V) to the lead(s) of the package, below the seating plane or not more than 2 mm above it. If the temperature of the soldering iron bit is less than 300 °C it may remain in contact for up to 10 seconds. If the bit temperature is between 300 and 400 °C, contact may be up to 5 seconds.

#### SO

#### REFLOW SOLDERING

Reflow soldering techniques are suitable for all SO packages.

Reflow soldering requires solder paste (a suspension of fine solder particles, flux and binding agent) to be applied to the printed-circuit board by screen printing, stencilling or pressure-syringe dispensing before package placement.

Several techniques exist for reflowing; for example, thermal conduction by heated belt. Dwell times vary between 50 and 300 seconds depending on heating method. Typical reflow temperatures range from 215 to 250 °C.

Preheating is necessary to dry the paste and evaporate the binding agent. Preheating duration: 45 minutes at 45 °C.

#### WAVE SOLDERING

Wave soldering techniques can be used for all SO packages if the following conditions are observed:

- A double-wave (a turbulent wave with high upward pressure followed by a smooth laminar wave) soldering technique should be used.
- The longitudinal axis of the package footprint must be parallel to the solder flow.
- The package footprint must incorporate solder thieves at the downstream end.

During placement and before soldering, the package must be fixed with a droplet of adhesive. The adhesive can be applied by screen printing, pin transfer or syringe dispensing. The package can be soldered after the adhesive is cured.

Maximum permissible solder temperature is 260 °C, and maximum duration of package immersion in solder is 10 seconds, if cooled to less than 150 °C within 6 seconds. Typical dwell time is 4 seconds at 250 °C.

A mildly-activated flux will eliminate the need for removal of corrosive residues in most applications.

#### REPAIRING SOLDERED JOINTS

Fix the component by first soldering two diagonally-opposite end leads. Use only a low voltage soldering iron (less than 24 V) applied to the flat part of the lead. Contact time must be limited to 10 seconds at up to 300  $^{\circ}$ C. When using a dedicated tool, all other leads can be soldered in one operation within 2 to 5 seconds between 270 and 320  $^{\circ}$ C.

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#### **DEFINITIONS**

Data sheet status			
Objective specification	This data sheet contains target or goal specifications for product development.		
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published late		
Product specification	This data sheet contains final product specifications.		

#### Limiting values

Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

#### **Application information**

Where application information is given, it is advisory and does not form part of the specification.

#### LIFE SUPPORT APPLICATIONS

These products are not designed for use in life support appliances, devices, or systems where malfunction of these products can reasonably be expected to result in personal injury. Philips customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Philips for any damages resulting from such improper use or sale.

#### PURCHASE OF PHILIPS I2C COMPONENTS



Purchase of Philips I<sup>2</sup>C components conveys a license under the Philips' I<sup>2</sup>C patent to use the components in the I<sup>2</sup>C system provided the system conforms to the I<sup>2</sup>C specification defined by Philips. This specification can be ordered using the code 9398 393 40011.